

# **HIT468**

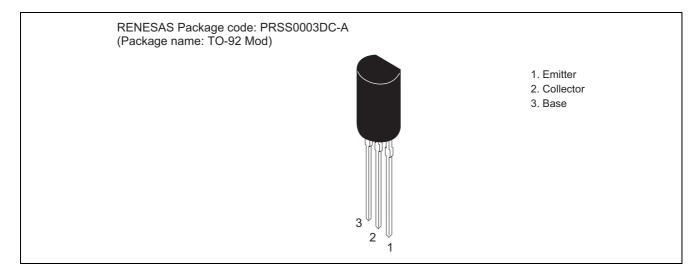
# Silicon NPN Epitaxial

REJ03G1502-0200 Rev.2.00 Mar 05, 2007

### **Features**

- Low frequency power amplifier
- Complementary pair with HIT562

### **Outline**



# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

ltem	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	45	V
Collector to emitter voltage	V <sub>CEO</sub>	25	V
Emitter to base voltage	V <sub>EBO</sub>	6	V
Collector current	Ic	1.0	Α
Collector peak current	I <sub>C (peak)</sub> *1	1.5	Α
Collector power dissipation	Pc	0.8	W
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

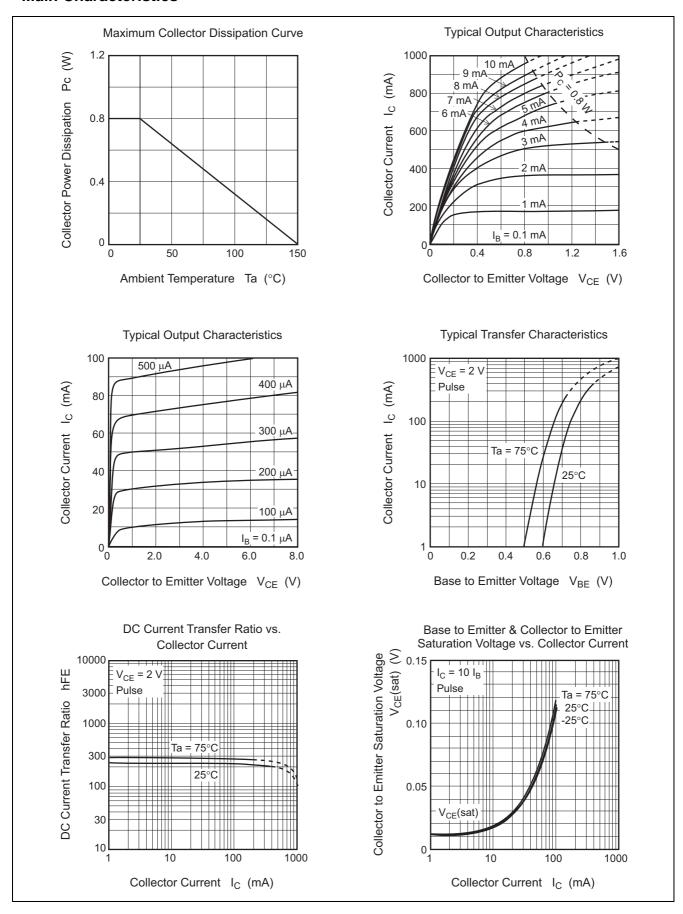
Note : 1. PW  $\leq$  10 ms, Duty cycle  $\leq$  20%

# **Electrical Characteristics**

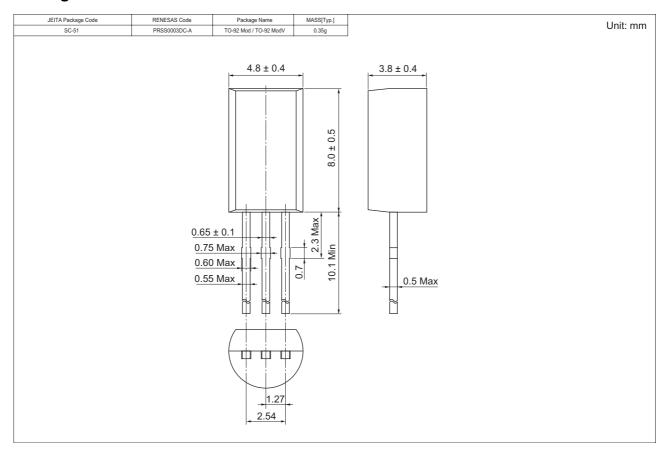
 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	V <sub>(BR)CBO</sub>	45	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	25	_	_	V	I <sub>C</sub> = 100 μA, R <sub>BE</sub> = ∞
Emitter to base breakdown voltage	V <sub>(BR)EBO</sub>	6	_	_	V	$I_E = 10 \mu\text{A},  I_C = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	500	nA	$V_{CB} = 45 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_	_	500	nA	$V_{EB} = 6 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE1</sub>	45	_	_	_	$V_{CE} = 1 \text{ V}, I_{C} = 5 \text{ mA}$
	h <sub>FE2</sub>	85	_	330	_	V <sub>CE</sub> = 1 V, I <sub>C</sub> = 100 mA
	h <sub>FE3</sub>	40	_	_	_	$V_{CE} = 1 \text{ V}, I_{C} = 800 \text{ mA}$
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	_	_	0.5	V	$I_C$ = 800 mA, $I_B$ = 80 mA
Base to emitter voltage	$V_{BE}$	_	_	1.0	V	$V_{CE} = 1 \text{ V}, I_{C} = 10 \text{ mA}$
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	_	_	1.2	V	I <sub>C</sub> = 800 mA, I <sub>B</sub> = 80 mA

### **Main Characteristics**



# **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container
HIT468-EQ	2500 pcs	Bulk, Vinyl Bag
HIT468TZ-EQ	2500 pcs	Hold Box, Radial Taping

Note: This product is designed for consumer use and not for automotive.

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